

NASA TECH BRIEF

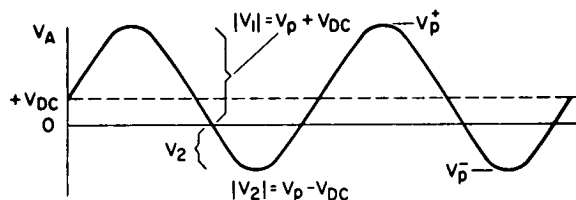
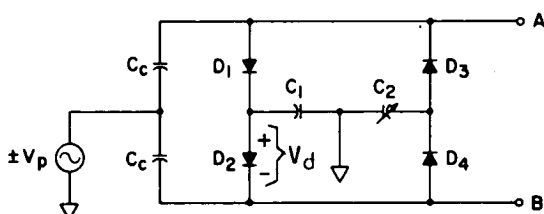
Ames Research Center



NASA Tech Briefs announce new technology derived from the U.S. space program. They are issued to encourage commercial application. Tech Briefs are available on a subscription basis from the National Technical Information Service, Springfield, Virginia 22151. Requests for individual copies or questions relating to the Tech Brief program may be directed to the Technology Utilization Office, NASA, Code KT, Washington, D.C. 20546.

Diode-Quad Bridge for Reactive Transducers and FM Discriminators

A new diode-quad bridge circuit has been developed for use with pressure-sensitive capacitive transducers, liquid-level measuring devices, proximity deflection sensors, and inductive displacement sensors. It may also be used as an FM discriminator and as a universal impedance bridge.



The circuit in the diagram provides an improvement over other recently developed circuits in at least one of the following respects: (1) The output is relatively independent of excitation frequency; (2) The circuit sensitivity is greater and is independent of waveform; (3) The circuit performs equally well with either capacitive-, resistive-, or inductive-type transducers; (4) The transducer may be conveniently grounded; (5) The circuit also functions as a tuned frequency discriminator by combining series or parallel inductors with C_1 and C_2 .

The diodes in the circuit perform as switches which conduct current in sequence. A typical input voltage waveform is also shown in the diagram; the waveform represents a sinusoidal excitation voltage and a positive DC output signal present on terminal A (the DC voltage at B is negative). Assuming that the capacitances of the coupling capacitors C_c are much greater than C_1 and C_2 , and that the circuit is unloaded, diode D_1 conducts when the applied voltage is sufficient to produce a forward bias condition and charges C_1 to the peak value V_1 while removing a quantity of charge from C_c equal to $V_1 C_1$. When the applied voltage decreases sufficiently, D_1 is turned off, and D_3 conducts as it becomes forward biased relative to the voltage on C_2 ; a peak value of V_2 is impressed on C_2 thereby replacing a quantity of charge on C_c equal to $V_2 C_2$. The net effect is that it appears as though a differential charge exists on C_c that is proportional to the charges on C_1 and C_2 . However, for steady-state conditions, the net transfer of charge from C_c is zero. Since the DC voltage component on C_c must then adjust to a level to satisfy the condition $Q_1 = Q_2$, it follows that $V_1 C_1 = V_2 C_2$. Also, it can be shown that the voltages between terminals A and B is

$$\frac{V_{DC}}{V_p - V_d} \bigg|_{AB} = \frac{2(C_1 - C_2)}{C_1 + C_2};$$

the terms in the voltage transfer function are identified in the diagram.

Examination of the voltage transfer function suggests that if C_1 and C_2 are nearly equal and have identical temperature coefficients, temperature changes will be self-canceling in the capacitive functions of

(continued overleaf)

the circuit; however, the diodes can produce considerable drift in the output if the diode-quad is not constructed of temperature-matched components.

Alternative embodiments of the circuit shown in the diagram can be formed by substituting resistors or parallel- and series-resonant LC elements in place of C_1 and C_2 , or other combinations of L, C, and R.

Note:

Requests for further information may be directed to:

Technology Utilization Officer
Ames Research Center
Moffett Field, California 94035
Reference: TSP 72-10691

Patent status:

Inquiries about obtaining rights for the commercial use of this invention may be made to:

Patent Counsel
Mail Code 200-11A
Ames Research Center
Moffett Field, California 94035

Source: Dean R. Harrison and
John Dimeff
Ames Research Center
(ARC-10364)